Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic
Overall Length:
0.076 inches
Terminal Length:
0.062 inches
Overall Diameter:
0.083 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
40.00 milliamperes forward current, average peak
Power Rating Per Characteristic:
2.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0